

PNP Epitaxial Silicon Transistor KSA1010

High Speed High Voltage Switching

- Industrial Use
- Complement to KSC2334

ABSOLUTE MAXIMUM RATINGS

 $(T_C = 25^{\circ}C \text{ unless otherwise noted.})$

Symbol	Parameter	Ratings	Unit
V_{CBO}	Collector-Base Voltage	-100	V
V _{CEO}	Collector-Emitter Voltage	-100	V
V _{EBO}	Emitter-Base Voltage	-7	V
I _C	Collector Current (DC)	-7	Α
I _{CP}	Collector Current (Pulse) (Note 1)	-15	Α
Ι _Β	Base Current	-3.5	Α
P _C	Collector Dissipation (T _C = 25°C)	40	W
	Collector Dissipation (T _A = 25°C)	1.5	W
T_J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. PW \leq 300 μ s, Duty Cycle \leq 10%.

1. Base 2. Collector 3. Emitter TO-220-3LD CASE 340AT

MARKING DIAGRAM



 $\begin{array}{ll} \text{YWW} &= \text{Date Code (Year \& Week)} \\ \text{ZZ} &= \text{Lot Run Traceability Code} \\ \text{A1010} &= \text{Specific Device Code} \\ \text{Y} &= \text{h}_{\text{FE}} \, \text{Grade} \\ \end{array}$

ORDERING INFORMATION

Device	Package	Shipping
KSA1010YTU	TO-220-3LD (Pb-Free)	1000 Units / Tube

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage	I _C = -5 A, I _{B1} = -0.5 A, L = 1 mH	-100	-	V
V _{CEX} (sus)1	Collector-Emitter Sustaining Voltage	$I_C = -5$ A, $I_{B1} = -I_{B2} = -0.5$ A, $V_{BE}(off) = 5$ V, L = 180 μ H, Clamped	-100	-	V
V _{CEX} (sus)2	Collector-Emitter Sustaining Voltage	$I_C = -10$ A, $I_{B1} = -1$ A, $I_{B2} = 0.5$ A, $V_{BE}(off) = 5$ V, L = 180 μ H, Clamped	-100	-	V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -100 \text{ V}, I_{E} = 0$	-	-10	μΑ
I _{CER}	Collector Cut-off Current	$V_{CE} = -100 \text{ V}, R_{BE} = 51 \Omega, T_{C} = 125^{\circ}\text{C}$	-	-1	mA
I _{CEX1}	Collector Cut-off Current	$V_{CE} = -100 \text{ V}, V_{BE}(\text{off}) = 1.5 \text{ V}$	-	-10	μΑ
I _{CEX2}	Collector Cut-off Current	$V_{CE} = -100 \text{ V}, V_{BE}(\text{off}) = 1.5 \text{ V}, T_{C} = 125^{\circ}\text{C}$	-	-1	mA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -5 \text{ V}, I_{C} = 0$	-	-10	μΑ
h _{FE1} h _{FE2} h _{FE3}	DC Current Gain (Note 2)	V _{CE} = -5 V, I _C = -0.5 A V _{CE} = -5 V, I _C = -3 A V _{CE} = -5 V, I _C = -5 A	40 40 20	200 –	
V _{CE} (sat)	Collector-Emitter Saturation Voltage (Note 2)	$I_C = -5 \text{ A}, I_B = -0.5 \text{ A}$	-	-0.6	V
V _{BE} (sat)	Base-Emitter Saturation Voltage (Note 2)	$I_C = -5 \text{ A}, I_B = -0.5 \text{ A}$	-	-1.5	V
t _{ON}	Turn On Time	$V_{CC} = -50 \text{ V}, I_{C} = -5 \text{ A},$	-	0.5	μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = -0.5 \text{ A},$ $R_{I} = 10 \Omega$	_	1.5	μs
t _F	Fall Time		_	0.5	μS

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: $PW \le 350 \mu s$, Duty Cycle $\le 2\%$.

h_{FE} Classification

Classification	R	0	Υ
h _{FE2}	40 ~ 80	60 ~ 120	100 ~ 200

KSA1010

TYPICAL CHARACTERISTICS

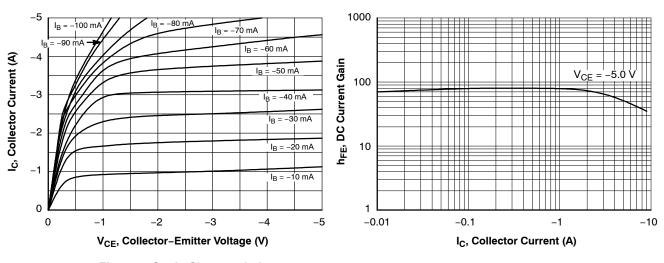


Figure 1. Static Characteristic

Figure 2. DC Current Gain

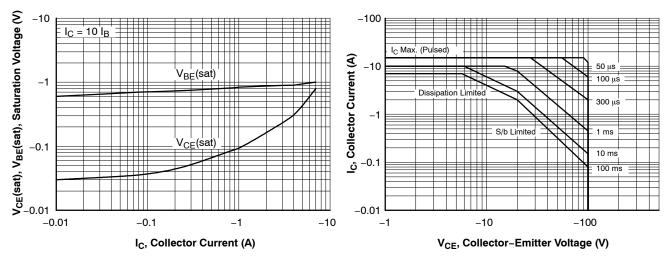


Figure 3. Base–Emitter Saturation Voltage Collector–Emitter Saturation Voltage

Figure 4. Safe Operating Area

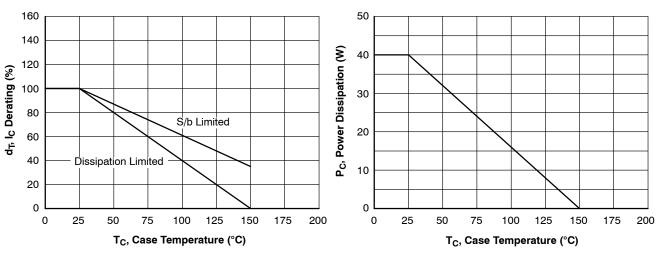
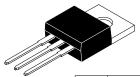


Figure 5. Derating Curve of Safe Operating Areas

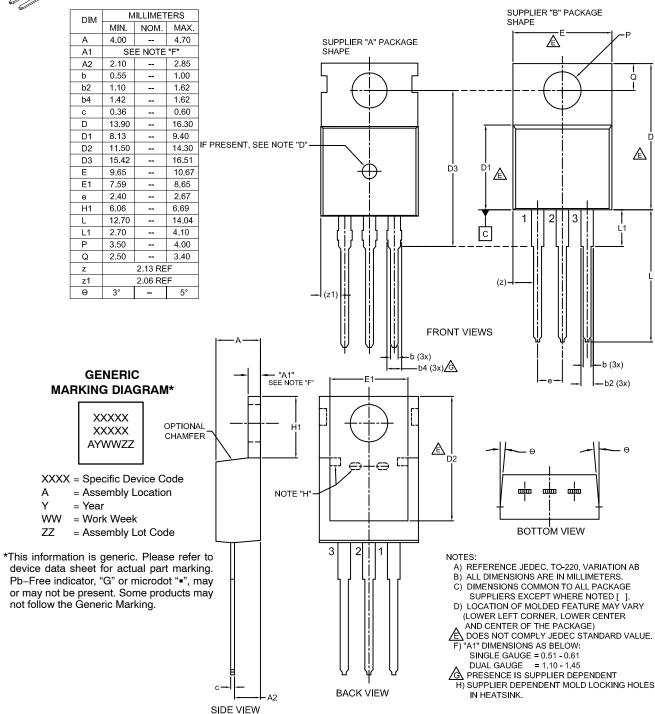
Figure 6. Power Derating





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